**Product data sheet** 

## 1. General description

NPN low  $V_{CEsat}$  transistor in a medium power SOT223 (SC-73) Surface-Mounted Device (SMD) plastic package.

PNP complement: PBSS5350Z-Q

### 2. Features and benefits

- · Low collector-emitter saturation voltage
- High collector current capability: I<sub>C</sub> and I<sub>CM</sub>
- High collector current gain (h<sub>FE</sub>) at high I<sub>C</sub>
- Higher efficiency leading to less heat generation
- Qualified according to AEC-Q101 and recommended for use in automotive applications

# 3. Applications

- Power management
  - · DC/DC converters
  - Supply line switching
  - Battery charger
  - Linear voltage regulation (LDO)
- Peripheral drivers
  - · Driver in low supply voltage applications, for example lamps, LEDs
  - · Inductive load driver, for example relays, buzzers, motors

## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
I <sub>C</sub>	collector current		-	-	3	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	5	Α
h <sub>FE</sub>	DC current gain	$V_{CE}$ = 2 V; $I_{C}$ = 500 mA; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	200	-	-	
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C$ = 2 A; $I_B$ = 200 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	110	145	mΩ



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# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	С
2	С	collector		
3	Е	emitter		B —
4	С	collector	1 2 3	Ė
			SC-73 (SOT223)	sym123

# 6. Ordering information

## **Table 3. Ordering information**

Type number	er Package						
	Name	Description	Version				
PBSS4350Z-Q		plastic, surface-mounted package with increased heatsink; 4 leads; 2.3 mm pitch; 6.5 mm x 3.5 mm x 1.65 mm body	SOT223				

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PBSS4350Z-Q	PB4350

# 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	60	V
$V_{CEO}$	collector-emitter voltage	open base		-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	6	V
I <sub>C</sub>	collector current			-	3	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	5	А
I <sub>BM</sub>	peak base current			-	1	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	1.35	W
			[2]	-	2	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>. Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

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## 9. Thermal characteristics

#### **Table 6. Thermal characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
11(J-a)	thermal resistance from	in free air	[1]	-	-	92	K/W
	junction to ambient		[2]	-	-	62.5	K/W

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>. Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

## 10. Characteristics

#### **Table 7. Characteristics**

Symbol	Parameter	Conditions	Mi	n Typ	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	100	nA
	current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	50	μA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	100	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = 2 V; $I_{C}$ = 500 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	200	) -	-	
		$V_{CE}$ = 2 V; $I_{C}$ = 1 A; pulsed; $t_{p} \le 300 \ \mu s$ ; δ ≤ 0.02; $T_{amb}$ = 25 °C	200	) -	-	
		$V_{CE}$ = 2 V; $I_{C}$ = 2 A; pulsed; $t_{p} \le 300 \ \mu s$ ; δ ≤ 0.02; $T_{amb}$ = 25 °C	100	) -	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C$ = 500 mA; $I_B$ = 50 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-	90	mV
		$I_C$ = 1 A; $I_B$ = 50 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-	170	mV
		$I_C$ = 2 A; $I_B$ = 200 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-	290	mV
R <sub>CEsat</sub>	collector-emitter saturation resistance		-	110	145	mΩ
V <sub>BEsat</sub>	base-emitter saturation voltage		-	-	1.2	V
$V_{BEon}$	base-emitter turn-on voltage	$V_{CE}$ = 2 V; $I_{C}$ = 1 A; pulsed; $t_{p} \le 300 \ \mu s$ ; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	-	1.1	V
f <sub>T</sub>	transition frequency	$V_{CE}$ = 5 V; $I_{C}$ = 100 mA; f = 100 MHz; $T_{amb}$ = 25 °C	100	) -	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB}$ = 10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; f = 1 MHz; $T_{amb}$ = 25 °C	-	-	30	pF

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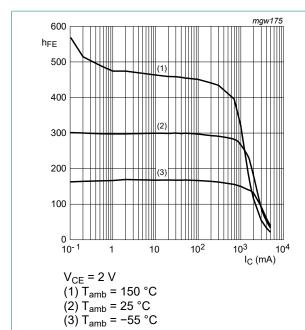


Fig. 1. DC current gain; typical values

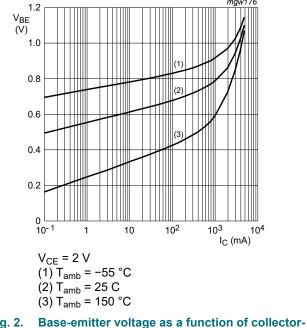


Fig. 2. Base-emitter voltage as a function of collectorcurrent; typical values

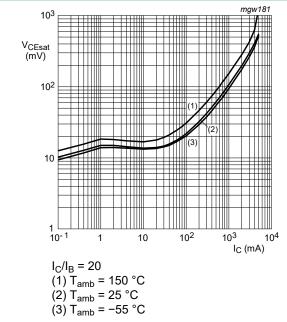


Fig. 3. Collector-emitter saturation as a function of collector current; typical values.

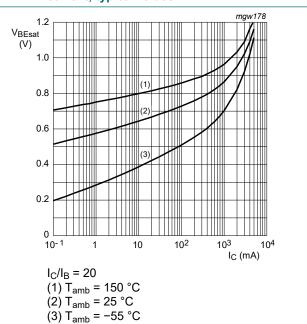
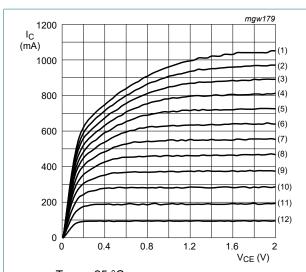


Fig. 4. Base-emitter saturation voltage as a function of collector current; typical values

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 $T_{amb}$  = 25 °C

(1)  $I_B = 3.96 \text{ mA}$ 

 $(2) I_B = 3.63 \text{ mA}$ 

 $(3) I_B = 3.30 \text{ mA}$ 

 $(4) I_B = 2.97 \text{ mA}$ 

 $(5) I_B = 2.64 \text{ mA}$ (6)  $I_B = 2.31 \text{ mA}$ 

 $(7) I_B = 1.98 \text{ mA}$ 

 $(8) I_B = 1.65 \text{ mA}$ 

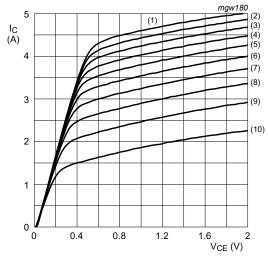
 $(9) I_B = 1.32 \text{ mA}$ 

 $(10) I_B = 0.99 mA$ 

 $(11) I_B = 0.66 \text{ mA}$ 

(12)  $I_B = 0.33 \text{ mA}$ 





 $T_{amb}$  = 25 °C

(1)  $I_B = 150 \text{ mA}$ 

(2) I<sub>B</sub>= 135 mA

 $(3) I_B = 120 \text{ mA}$ 

 $(4) I_B = 105 \text{ mA}$ 

 $(5) I_B = 90 \text{ mA}$ 

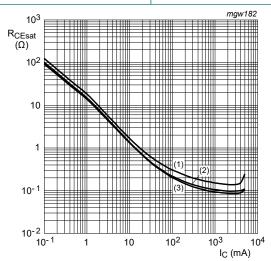
(6)  $I_B = 75 \text{ mA}$ 

 $(7) I_B = 60 \text{ mA}$ 

(8)  $I_B = 45 \text{ mA}$ 

(9)  $I_B = 30 \text{ mA}$  $(10) I_B = 15 mA$ 

Fig. 6. Collector current as a function of collectoremitter voltage; typical values.



 $I_C/I_B = 20$  (1)  $T_{amb} = 150 \, ^{\circ}C$ 

(2) T<sub>amb</sub> = 25 °C

(3)  $T_{amb} = -55 \, ^{\circ}C$ 

Collector-emitter equivalent on-resistance as a function of collector current; typical values

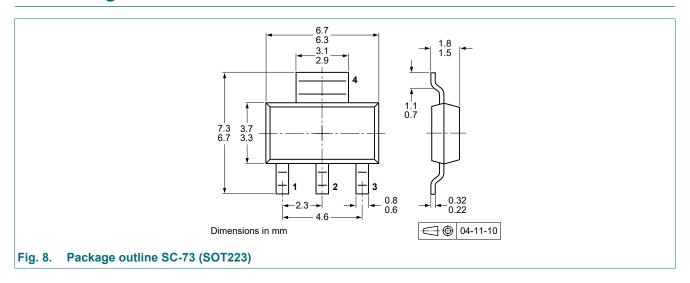
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## 11. Test information

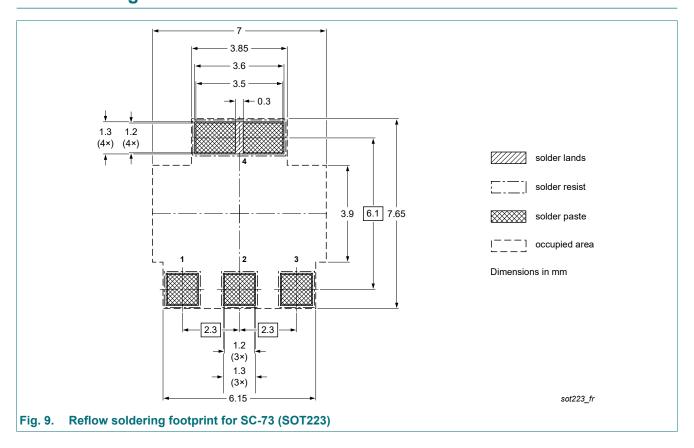
### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

# 12. Package outline

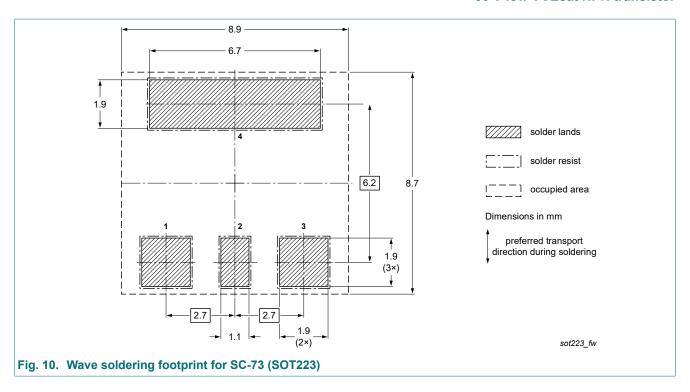


## 13. Soldering



PBSS4350Z-Q

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# 14. Revision history

### **Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS4350Z-Q v.1	20230919	Product data sheet	-	-

#### 50 V low VCEsat NPN transistor

## 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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